DC/DC Transformer for SCALE-iDriver Gate Driver ICs
Providing Reinforced Isolation up to 1200 V

## Product Highlights

## Highly Flexible, Compact Footprint

- Dual channel DC/DC transformer optimized for forward converters
- Reinforced isolation for $600 \mathrm{~V} / 650 \mathrm{~V} / 1200 \mathrm{~V}$ IGBT and SiC MOSFET applications
- For use with all SCALE-iDriver ${ }^{\text {Tm }}$ ICs
- Choice of primary-to-secondary winding ratios
- $-40^{\circ} \mathrm{C}$ to $105^{\circ} \mathrm{C}$ operating temperature range
- Light weight - only 9 g
- Less than 10 pF coupling capacitance

Full Safety and Regulatory Compliance

- EN 61558-2-16+A1:2013 compliant
- $100 \%$ HIPOT tested at 5.4 kV RMS 1 s (primary-to-secondary), 2.7 kV RMS 1s (secondary-to-secondary)
- High shock and vibration robustness
- Easily meets IEC 60721-3-3 - Class 3M8 and IEC 60721-3-5 Class 5M3
- VDE approved
- UL1446 approved


## Green Package

- Halogen free and RoHS compliant


## Applications

- General industrial applications
- Variable frequency and servo drives
- Static VAR compensators and active power filters
- Uninterruptible power supplies
- PV inverters
- Welding inverters


## Description

The innovative transformer "isolated wire-in-wire" structure provides excellent reliability and strong isolation combined with low coupling capacitance. The high isolation capability is achieved without the need for mold compound. SIT12xxI transformers are UL and VDE approved, simplifying safety certification and reducing time-to-market. The SIT12xxI is a DC/DC transformer that delivers a secondary-side voltage of 25 V to support SCALE-iDriver gate driver ICs. SIT12xxI transformers are available with different winding ratios to accommodate a primary-side supply voltage of either 5 V or 15 V .


Figure 1. Typical Application Schematic.


Figure 2. SIT1217I and SIT1253I Transformers.

## Product Portfolio

| Product $^{3}$ | Power | Primary-Side Supply |
| :--- | :---: | :---: |
| SIT1253I | $2 \times 1.3 \mathrm{~W}$ | 5 V |
| SIT1217I | $2 \times 1.3 \mathrm{~W}$ | 15 V |

Table 1. SIT12xxI Transformer Portfolio.

## Pin Functional Description

## Pin 1

Start of primary-side winding W1.

## Pin 2

Start of primary-side winding W2.

## Pin 3

End of primary-side winding W1.

## Pin 4

End of primary-side winding W2.

## Pin 5

Start of secondary-side winding W3.

## Pin 6

End of secondary-side winding W3.

## Pin 9

Start of secondary-side winding W4.

## Pin 10

End of secondary-side winding W4.


Figure 3. Top View Footprint and Pin Assignment.

| Ratios |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | W1 | W2 | W3 | W4 |
| W1 | X | 1 | 5.33 | 5.33 |
| W2 | 1 | X | 5.33 | 5.33 |
| W3 | 0.19 | 0.19 | X | 1 |
| W4 | 0.19 | 0.19 | 1 | X |

Table 2. Ratios SIT1253I.

| Ratios |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | W1 | W2 | W3 | W4 |
| W1 | X | 1 | 1.73 | 1.73 |
| W2 | 1 | x | 1.73 | 1.73 |
| W3 | 0.58 | 0.58 | x | 1 |
| W4 | 0.58 | 0.58 | 1 | X |

Table 3. Ratios SIT1217I.

## SIT12xxI

## Application Example and Component Selection

The transformers of the SIT12xxI family are designed for single switch forward converter topologies. Figure 4 shows an application example using SIT1253I, where the primary-side supply voltage is set to 5 V (with reference to GND). Figure 5 shows an application example using SIT1217I where the primary-side supply voltage is set to 15 V (with reference to GND).

For both designs, the input capacitors ( C 1 to C 8 ) must be selected according to target power. For full power (1.3 W per output channel) an overall capacitance of $35 \mu \mathrm{~F}$ is required. The use of eight $4.7 \mu \mathrm{~F}$ capacitors in SMD 1206 packages is recommended in this case. The voltage rating of the capacitors must also be considered. The use of 16 V devices when using 5 V primary-side supply voltage (SIT1253I) and 25 V devices when a 15 V primary-side supply voltage (SIT1217I) is recommended.

The single forward switch S 1 is controlled by a standard timer IC, here a TI TLC555Q is used (a CPLD, FPGA or micro controller can also be used). Resistors $R_{1}, R_{2}$ and $C_{9}$ and connecting the trigger input to the threshold-input causes the timer to self-trigger and run as a multi-vibrator. For SIT1253I and SIT1217I the recommended switching frequencies are 150 kHz and 260 kHz respectively. The duty cycle is set to $45 \%$ in both examples. Measurements across application conditions should be made to confirm safe operation.

To drive the forward switch, a standard MOSFET driver is connected to the output of the TLC555Q. An MCP1402 IC is recommended for this. To adjust the switching behavior of S1, R3 is placed between the output of MCP1402 and the MOSFETs gate terminal.


Figure 4. Application Example SIT1253I with 5 V Supply Voltage.


Figure 5. Application Example SIT1217I with 15 V Supply Voltage.

| Pin | Return to Pin | Recommended Value | Symbol | Notes |
| :---: | :---: | :---: | :---: | :---: |
| VSUPPLY | GND | $8 \times 4.7 \mu \mathrm{~F}$ | $\mathrm{C}_{1}$ to $\mathrm{C}_{8}$ | The use of X7S / $10 \%$ in a 1206 package is recommended with 16 V rated voltage for SIT1253I and 25 V rated voltage for SIT1217I. |
| TRIG | GND | $1 \mathrm{nF} / 330 \mathrm{pF}$ | C9 | The use of NPO or C0G / $50 \mathrm{~V} / 5 \%$ in a 0603 package is recommended. 1 nF to be used for SIT1253I and 330 pF for SIT1217I. |
| VSUPPLY | GND | 100 nF | $\mathrm{C}_{10}$ | The use of $\mathrm{X} 7 \mathrm{R} / 10 \%$ in a 0603 package is recommended with 16 V rated voltage for SIT1253I and 25 V rated voltage for SIT1217I. |
| CONT | GND | 10 nF | $\mathrm{C}_{11}$ | The use of X7R / $25 \mathrm{~V} / 10 \%$ in a 0603 package is recommended. |
| VSUPPLY | GND | 100 nF | $\mathrm{C}_{12}$ | The use of $X 7 R$ / $10 \%$ in a 0603 package is recommended with 16 V rated voltage for SIT1253I and 25 V rated voltage for SIT1217I. |
| VSUPPLY | DISCH | $2.4 \mathrm{k} \Omega / 5.1 \mathrm{k} \Omega$ | $\mathrm{R}_{1}$ | The use of $1 \% / 0.1 \mathrm{~W} / 50 \mathrm{~V}$ thick film chip resistors in a 0603 package is recommended, with a value of $2.4 \mathrm{k} \Omega$ for SIT1253I and $5.1 \mathrm{k} \Omega$ with SIT1217I. |
| TRIG | DISCH | $4.3 \mathrm{k} \Omega / 7.5 \mathrm{k} \Omega$ | $\mathrm{R}_{2}$ | The use of $1 \% / 0.1 \mathrm{~W} / 50 \mathrm{~V}$ thick film chip resistors in a 0603 package is recommended, with a value of $4.3 \mathrm{k} \Omega$ for SIT1253I and $7.5 \mathrm{k} \Omega$ with SIT1217I. |
| OUT MCP1402 | $\begin{gathered} \mathrm{G} \\ \mathrm{~S} 1 \end{gathered}$ | $10 \Omega$ | $\mathrm{R}_{3}$ | The use of $1 \% / 0.1 \mathrm{~W} / 50 \mathrm{~V}$ thick film chip resistors in a 0603 package is recommended. |
| DISCH | TRIG | BAS316 | $\mathrm{D}_{1}$ | The use of BAS316 $100 \mathrm{~V} / 250 \mathrm{~mA} / 400 \mathrm{~mW}$ of NXP in a SOD323 package is recommended. |
| GND | $\begin{aligned} & \text { Pin } 2 \\ & \text { W2 } \end{aligned}$ | STPS1150A | $\mathrm{D}_{2}$ | The use of STPS1150A $150 \mathrm{~V} / 1 \mathrm{~A} / 620 \mathrm{mV}$ @ $I_{F}=1 \mathrm{~A}$ of STMicroelectronics in a SMA package is recommended. |
| $\begin{aligned} & \text { Pin } 9 \\ & \text { W4 } \end{aligned}$ | VISO1 | STPS1150A | $\mathrm{D}_{3}$ | The use of STPS1150A $150 \mathrm{~V} / 1 \mathrm{~A} / 620 \mathrm{mV}$ @ $I_{F}=1 \mathrm{~A}$ of STMicroelectronics in a SMA package is recommended. |
| $\begin{gathered} \text { Pin } 5 \\ \text { W3 } \end{gathered}$ | VISO2 | STPS1150A | $\mathrm{D}_{4}$ | The use of STPS1150A $150 \mathrm{~V} / 1 \mathrm{~A} / 620 \mathrm{mV}$ @ $I_{F}=1 \mathrm{~A}$ of STMicroelectronics in a SMA package is recommended. |
| $\begin{aligned} & \text { Pin } 3 \\ & \text { W1 } \end{aligned}$ | GND | DMT10H015LSS | $\mathrm{S}_{1}$ | The use of DMT10H015LSS $100 \mathrm{~V} / 8.3 \mathrm{~A} /$ 1.2 W / $9.7 \mathrm{~m} \Omega$ of Diodes Incorporated in a SO-8 case is recommended. |
| $\begin{aligned} & \text { Pin } 3 \\ & \text { W1 } \end{aligned}$ | R4 | 4.7 nF | $\mathrm{C}_{12}$ | Only for SIT1253I: The use of X7S / $10 \%$ in a 1206 package is recommended with 50 V rated voltage |
| $\mathrm{C}_{12}$ | GND | $3 \Omega$ | $\mathrm{R}_{4}$ | Only for SIT1253I: The use of $1 \% / 0.1$ W / 50 V thick film chip resistors in a 0603 package is recommended |
| - | - | TLC555Q | IC1 | The use of TLC555Q of TI in a SOIC D package is recommended. |
| - | - | MCP1402 | IC2 | The use of MCP1402 of Microchip in a SOT23-5 package is recommended. |

Table 4. PCB Layout and Component Guidelines.

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Environmental Conditions |  |  |  |  |  |  |
| Operating Ambient Temperature | $\mathrm{T}_{\mathrm{A}}$ |  | -40 |  | 105 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | T | Packaged | -30 |  | 70 | ${ }^{\circ} \mathrm{C}$ |
| Climatic Category |  | IEC 60068-1 |  | / 125 / 5 |  |  |
| Electrical Characteristics |  |  |  |  |  |  |
| Turns Ratio |  | W1 : W2: W3: W4 SIT1253I |  | $\begin{gathered} 6: 6: \\ 32: 32 \end{gathered}$ |  |  |
|  |  | $\begin{gathered} \text { W1 : W2 : W3 : W4 } \\ \text { SIT1217I } \end{gathered}$ |  | $\begin{gathered} 11: 11: \\ 19: 19 \end{gathered}$ |  |  |
| Main Inductance | L | $\begin{gathered} \text { SIT1253I, @ } 25^{\circ} \mathrm{C} \\ \mathrm{~W} 1, \mathrm{w} 2 @ \mathrm{f}_{\mathrm{s}}=100 \mathrm{kHz}, \mathrm{~V}_{\mathrm{o}} \leq 50 \mathrm{mV} \end{gathered}$ | 32.5 | 50 | 67.5 | $\mu \mathrm{H}$ |
|  |  | $\begin{gathered} \text { SIT1217I, @ } 25^{\circ} \mathrm{C} \\ \mathrm{~W} 1, \mathrm{w} 2 @ \mathrm{f}_{\mathrm{s}}=100 \mathrm{kHz}, \mathrm{~V}_{0} \leq 50 \mathrm{mV} \end{gathered}$ | 110.5 | 170 | 229.5 |  |
| Leakage Inductance | $\mathrm{L}_{\text {LEAK }}$ | SIT1253I, @ $25^{\circ} \mathrm{C}$ <br> W1 / W2 (W3 and W4 shorted) $\mathrm{fs}=100 \mathrm{kHz}, \mathrm{~V}_{0} \leq 50 \mathrm{mV}$ |  |  | 250 | nH |
|  |  | $\text { SIT1217I, @ } 25^{\circ} \mathrm{C}$ <br> W1 / W2 (W3 and W4 shorted) $\mathrm{fs}=100 \mathrm{kHz}, \mathrm{~V}_{0} \leq 50 \mathrm{mV}$ |  |  | 600 |  |
| Coupling Capacitance | $\mathrm{C}_{\mathrm{k}}$ | $\begin{gathered} \mathrm{W} 1 / \mathrm{W} 2-\mathrm{W} 3 / \mathrm{W} 4 \\ \mathrm{fs}=100 \mathrm{kHz}, \mathrm{~V}_{0}=50 \mathrm{mV} \end{gathered}$ |  |  | 10 | pF |
| Resistance | $\mathrm{R}_{\mathrm{DC} 1}$ | SIT1253I, W1 @ $25^{\circ} \mathrm{C}$ |  |  | 24 | $\mathrm{m} \Omega$ |
|  |  | SIT1217I, W1 @ $25^{\circ} \mathrm{C}$ |  |  | 95 |  |
|  | $\mathrm{R}_{\mathrm{DC} 2}$ | SIT1253I, W2 @ $25^{\circ} \mathrm{C}$ |  |  | 24 |  |
|  |  | SIT1217I, W2 @ $25^{\circ} \mathrm{C}$ |  |  | 95 |  |
|  | $\mathrm{R}_{\mathrm{DC} 3}$ | SIT1253I, W3 @ $25^{\circ} \mathrm{C}$ |  |  | 1.2 | $\Omega$ |
|  |  | SIT1217I, W3 @ $25^{\circ} \mathrm{C}$ |  |  | 0.7 |  |
|  | $\mathrm{R}_{\mathrm{DC} 4}$ | SIT1253I, W4 @ $25^{\circ} \mathrm{C}$ |  |  | 1.2 |  |
|  |  | SIT1217I, W4 @ $25^{\circ} \mathrm{C}$ |  |  | 0.7 |  |
| Power | $\mathrm{P}_{\text {тот }}$ | Per Channel |  |  | 1.3 | W |
| Mechanical Characteristics |  |  |  |  |  |  |
| Length | L |  | 25.4 | 26 | 26.15 | mm |
| Width | W |  |  |  | 23.5 | mm |
| Height | H |  |  |  | 16.5 | mm |
| Weight | m | SIT1253I |  | 9.4 |  | g |
|  |  | SIT1217I |  | 9.0 |  |  |


| Parameter | Symbol |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |

Dimensions and Markings




Figure 6. Dimensions and Markings of SIT1217I.





Figure 7. Dimensions and Markings of SIT1253I.

## Direction of Feed



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Figure 9. Tape Dimension Index.

| Package Type | Tape Size | $\mathrm{A}_{0}$ | $B_{0}$ | $B_{1}$ | D | $\mathrm{D}_{1}$ | E | F | K |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 44 mm | 22.6-23 | 27.2-27.6 | 32.84 typ | 1.5-1.6 | N/A | 1.65-1.85 | 20.1-20.3 | 17.6 Max |
| Package Type | Tape Size | $\mathrm{K}_{0}$ | P | $\mathbf{P}_{0}$ | $\mathrm{P}_{2}$ | R | t | $\mathrm{t}_{1}$ | W |
|  | 44 mm | 17-17.4 | 31.9-32.1 | 3.9-4.1 | 1.85-2.15 | 60 | 0.45-0.55 | 0.05 typ | 43.7-44.3 |

Table 5. Tape Dimension (in mm).

## SIT12xxI


(measured at hub)

Figure 10. Tape Dimension Index.

| Package Type | Tape <br> Size | $\mathbf{A}$ | $\mathbf{B}$ | $\mathbf{C}$ | $\mathbf{D}$ | $\mathbf{G}$ | $\mathbf{N}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 44 mm | $328-332$ | $2.1-2.5$ | $12.75-13.25$ | $21.4-21.9$ | $44.4-46.4$ | 100 Min |

Table 6. Reel Dimensions.

## SIT12xxI

## Solder Temperature Profiles



Figure 11. Solder Profiles According to JEDEG J-STD 020C / Reflow.


Figure 12. Recommended Reflow Profile for SMD-Components in Plastic Cases.


Figure 13. Solder Profiles According to BS CECC 00802 / Wave.

## Regulatory Information Table

| VDE | UL |
| :--- | :--- |
| DIN EN 61558-1 Safety of power transformers, power supplies, <br> reactors and similar products - Part 1: General requirements and <br> tests | UL 61800-5-1 Adjustable Speed Electrical Power Drive Systems <br> - Part 5-1: Safety Requirements - Electrical, Thermal and Energy |
| Certificate No. 40048903 | UL 1446 Systems of insulating materials |

## Part Ordering Information



| Revision | Notes | Date |
| :---: | :--- | :---: |
| B | Code A release. | $02 / 19$ |
| C | Updated Pin Description of pins 5, 6, 9, 10 and pin assignment in Figure 3. | $08 / 20$ |

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[^0]:    Figure 8. Part Orientation.

